2SK3796



N-Channel JFET 30V, 0.6 to 3.0mA, 6.5mS, SMCP

http://onsemi.com

Applications

· Low-frequency general-purpose amplifier, impedance conversion, analog switches applications

Features

- · Small IGSS
- · Small Ciss

Specifications

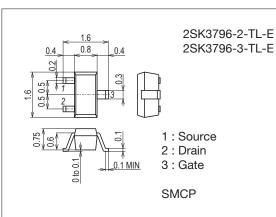
Absolute Maximum Ratings at Ta=25°C

| Parameter | Symbol | Conditions | Ratings | Unit |
|-----------------------------|------------------|------------|-------------|------|
| Drain-to-Source Voltage | V _{DSX} | | 30 | V |
| Gate-to-Drain Voltage | V _{GDS} | | -30 | V |
| Gate Current | IG | | 10 | mA |
| Drain Current | ID | | 10 | mA |
| Allowable Power Dissipation | PD | | 100 | mW |
| Junction Temperature | Tj | | 150 | °C |
| Storage Temperature | Tstg | | -55 to +150 | °C |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Package Dimensions

unit : mm (typ) 7013A-011

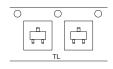


Product & Package Information

• Package : SMCP

• JEITA, JEDEC : SC-75, SOT-416 • Minimum Packing Quantity : 3,000 pcs./reel

Packing Type: TL





Marking

Electrical Connection



ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

Electrical Characteristics at Ta=25°C

| Parameter | Symbol | Conditions | Ratings | | | Unit |
|--|-----------------------|---|---------|-------|------|------|
| | | | min | typ | max | Oill |
| Gate-to-Drain Breakdown Voltage | V(BR)GDS | I _G =-10μA, V _{DS} =0V | -30 | | | V |
| Gate Cutoff Current | IGSS | VGS=-20V, VDS=0V | | | -1.0 | nA |
| Cutoff Voltage | V _{GS} (off) | V _{DS} =10V, I _D =1μA | -0.18 | -0.95 | -2.2 | V |
| Drain Current | IDSS | V _{DS} =10V, V _{GS} =0V | 0.6* | | 3.0* | mA |
| Forward Transfer Admittance | yfs | V _{DS} =10V, V _{GS} =0V, f=1kHz | 3.0 | 6.5 | | mS |
| Input Capacitance | Ciss | V _{DS} =10V, V _{GS} =0V, f=1MHz 4 | | | pF | |
| Reverse Transfer Capacitance | Crss | V _{DS} =10V, V _{GS} =0V, f=1MHz | | | pF | |
| Static Drain-to-Source On-State Resistance | R _{DS} (on) | V _{DS} =10mV, V _{GS} =10V | | 200 | | Ω |

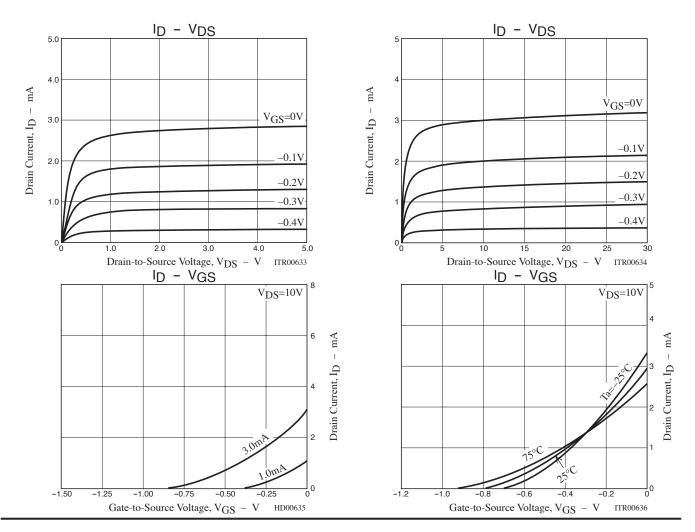
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

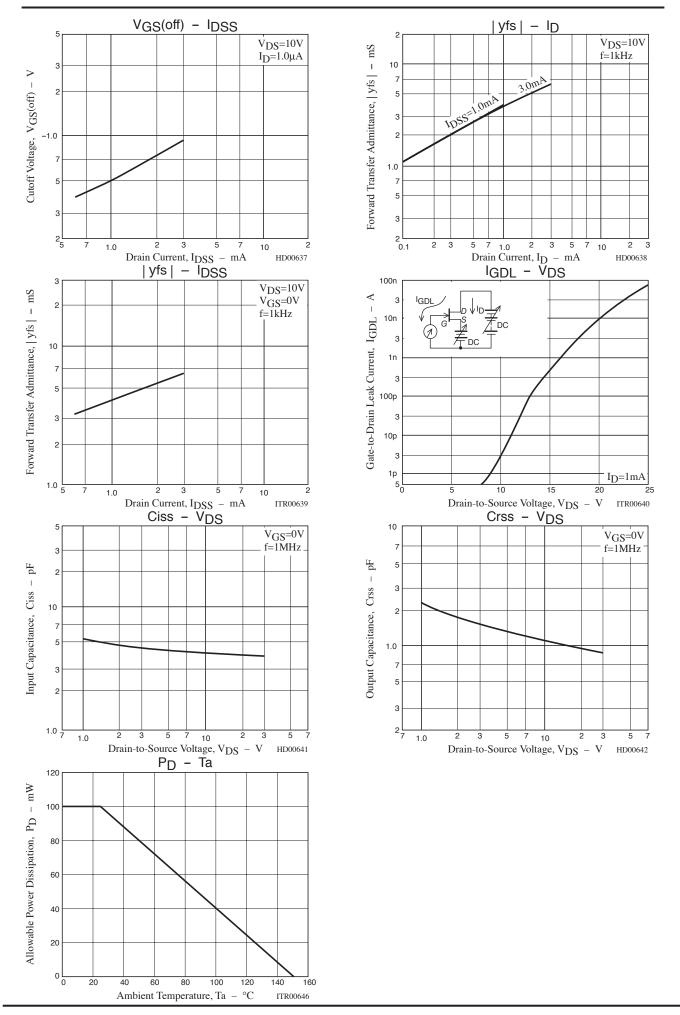
*: The 2SK3796 is classified by IDSS as follows: (unit: mA)

| Rank | 2 | 3 |
|------|------------|------------|
| IDSS | 0.6 to 1.5 | 1.2 to 3.0 |

Ordering Information

| Device | Package | Shipping | memo | |
|----------------|---------|----------------|---------|--|
| 2SK3796-2-TL-E | SMCP | 3,000pcs./reel | Db Free | |
| 2SK3796-3-TL-E | SMCP | 3,000pcs./reel | Pb Free | |



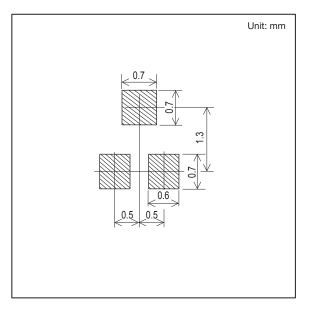


Outline Drawing

2SK3796-2-TL-E, 2SK3796-3-TL-E

Mass (g) Unit 0.003 *For reference mm

Land Pattern Example



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